

Binding energy (eV)

3000

2000

1000

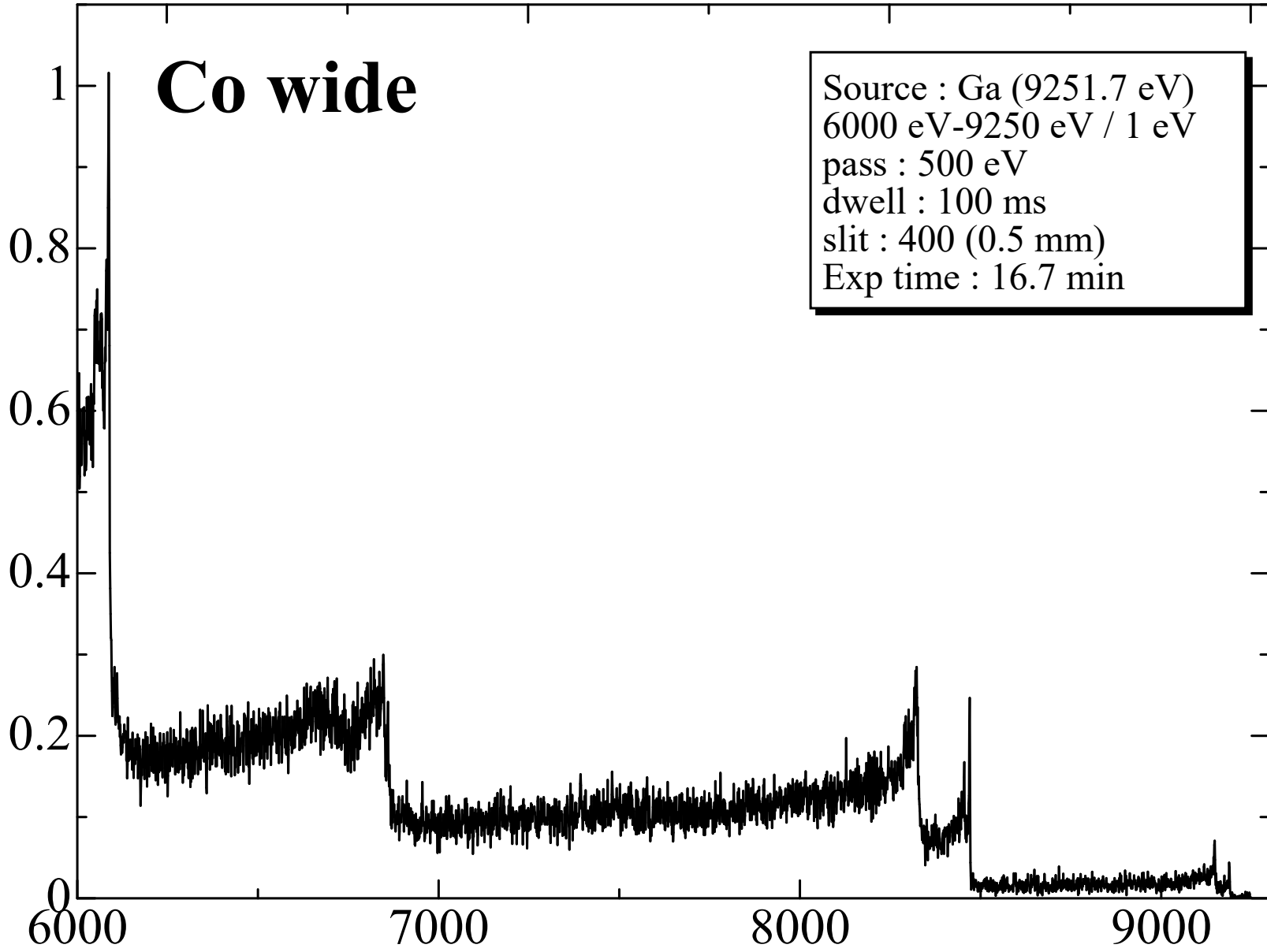
0

$[\times 10^4]$

Photoelectron intensity (count)

Co wide

Source : Ga (9251.7 eV)
6000 eV-9250 eV / 1 eV
pass : 500 eV
dwell : 100 ms
slit : 400 (0.5 mm)
Exp time : 16.7 min



6000

7000

8000

9000

Kinetic energy (eV)